NSN 5961-00-846-0169

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View Online at https://aerobasegroup.com/nsn/5961-00-846-0169 **Inclosure Material:** Metal **Overall Length:** 0.360 inches **Overall Diameter:** 0.625 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 28.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 3.50 amperes source cutoff current **Power Rating Per Characteristic:** 34.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release2778 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No